

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 1(50)
Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03	FCC ID L6ARBU20CW

Annex A: Measurement data and plots

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 2(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

A.3 RF emission field plots

For plots where the probe was rotated, an arrow is drawn to showing location of the probe rotation after the exclusion block.

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 3(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 4:51:45 PM

Test Laboratory: RTS

File Name: [HAC E CDMA800 spkr cent low chan RC1 SO2.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC E Device

Communication System: CDMA 800; Frequency: 824.7 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 12/03/2007
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

E Scan - ER probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement grid:

dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (measured) = 74.0 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 80.2 V/m; Power Drift = -0.014 dB

Maximum value of Total (measured) = 73.6 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 59.1 V/m

Probe Modulation Factor = 0.800

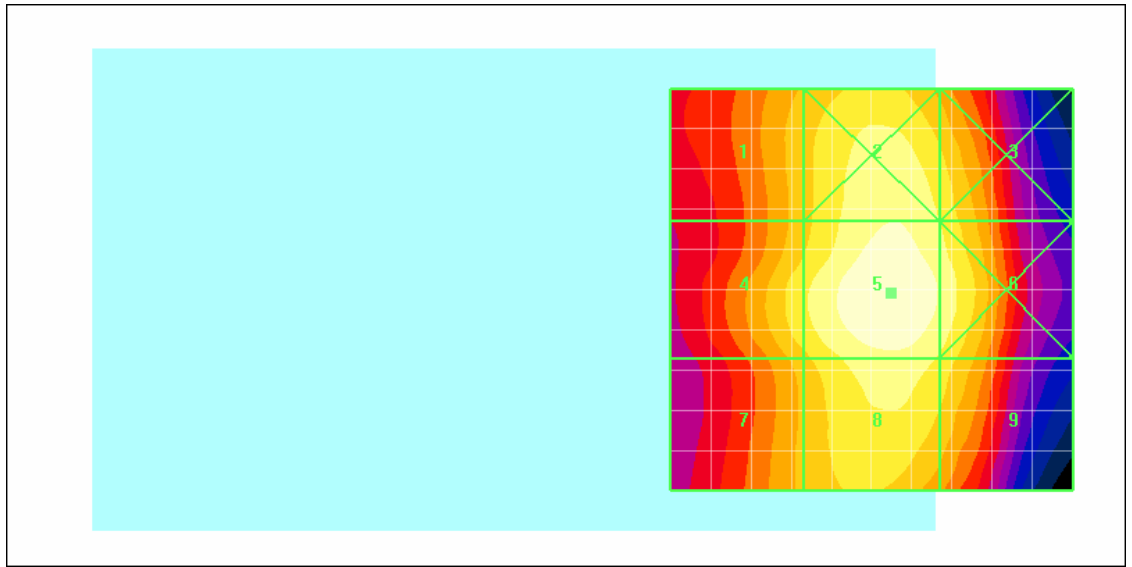
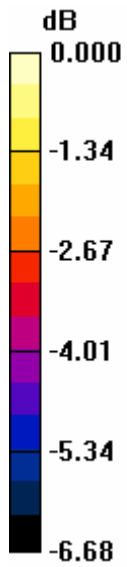
Reference Value = 80.2 V/m; Power Drift = -0.014 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid	Grid	Grid
49.8	56.2	53.3
Grid	Grid	Grid
52.9	59.1	55.8
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 4(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 59.1V/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 5(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 4:59:47 PM

Test Laboratory: RTS

File Name: [HAC E CDMA800 spkr cent mid chan RC1 SO2.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC E Device

Communication System: CDMA 800; Frequency: 836.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 12/03/2007
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

E Scan - ER probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement grid:

dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (measured) = 77.3 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 85.1 V/m; Power Drift = -0.157 dB

Maximum value of Total (measured) = 77.6 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 62.3 V/m

Probe Modulation Factor = 0.800

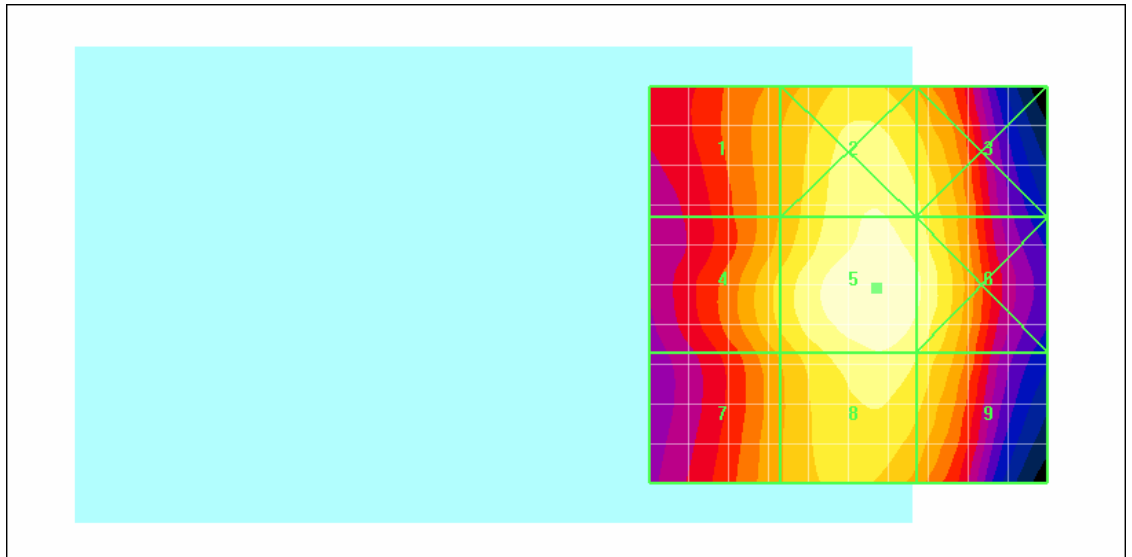
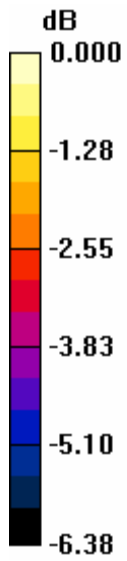
Reference Value = 85.1 V/m; Power Drift = -0.157 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid	Grid	Grid
51.5	59.5	57.4
Grid	Grid	Grid
54.9	62.3	60.0
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 6(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 62.3V/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 7(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 4:09:42 PM

Test Laboratory: RTS

File Name: [HAC E CDMA800 spkr cent high chan RC1 SO2.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC E Device

Communication System: CDMA 800; Frequency: 848.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 12/03/2007
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

E Scan - ER probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement grid:

dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (measured) = 81.0 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 87.0 V/m; Power Drift = 0.020 dB

Maximum value of Total (measured) = 80.6 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 64.7 V/m

Probe Modulation Factor = 0.800

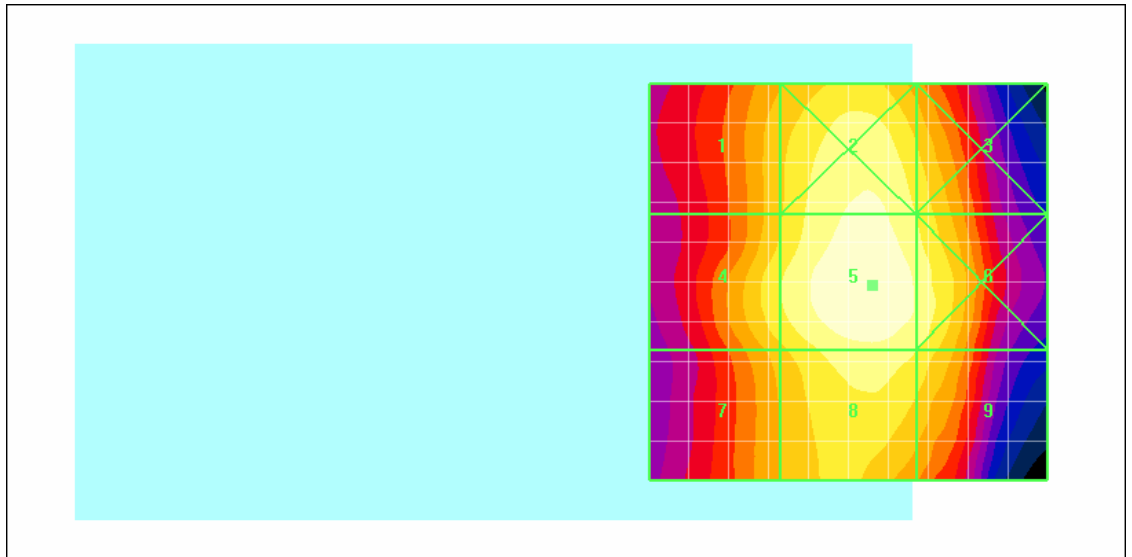
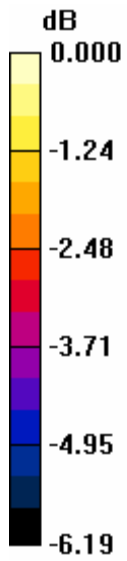
Reference Value = 87.0 V/m; Power Drift = 0.020 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid	Grid	Grid
55.9	62.3	58.8
Grid	Grid	Grid
58.8	64.7	61.5
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 8(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 64.7V/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 9(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 07/01/2008 9:49:17 AM

Test Laboratory: RTS

File Name: [HAC E CDMA800 spkr cent high chan RC1 SO3 1/8th 01 07 08.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC E Device

Communication System: CDMA 800; Frequency: 848.52 MHz; Duty Cycle: 1:8

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 12/03/2007
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

E Scan - ER probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement grid:

dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (measured) = 38.6 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 43.3 V/m; Power Drift = 0.018 dB

Maximum value of Total (measured) = 42.0 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 88.6 V/m

Probe Modulation Factor = 2.10

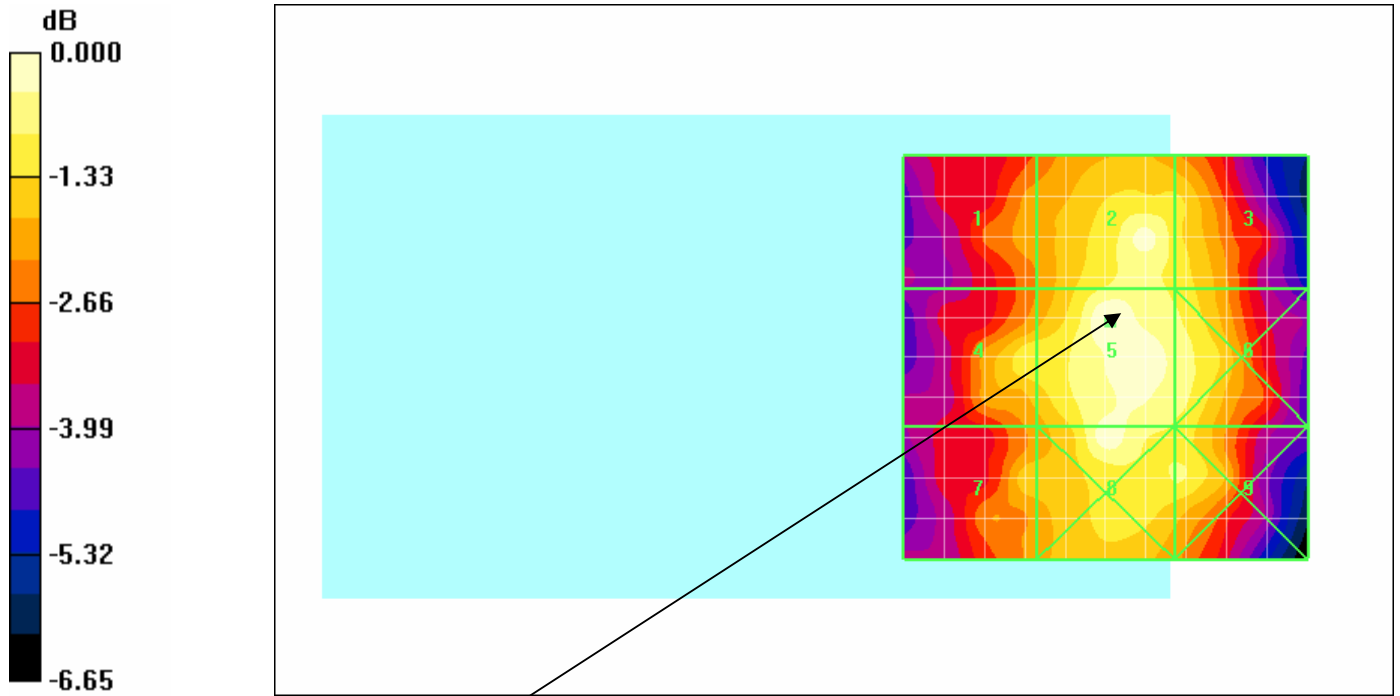
Reference Value = 43.3 V/m; Power Drift = 0.018 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid	Grid	Grid
71.8	85.8	79.3
Grid	Grid	Grid
79.9	88.6	83.3
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 10(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

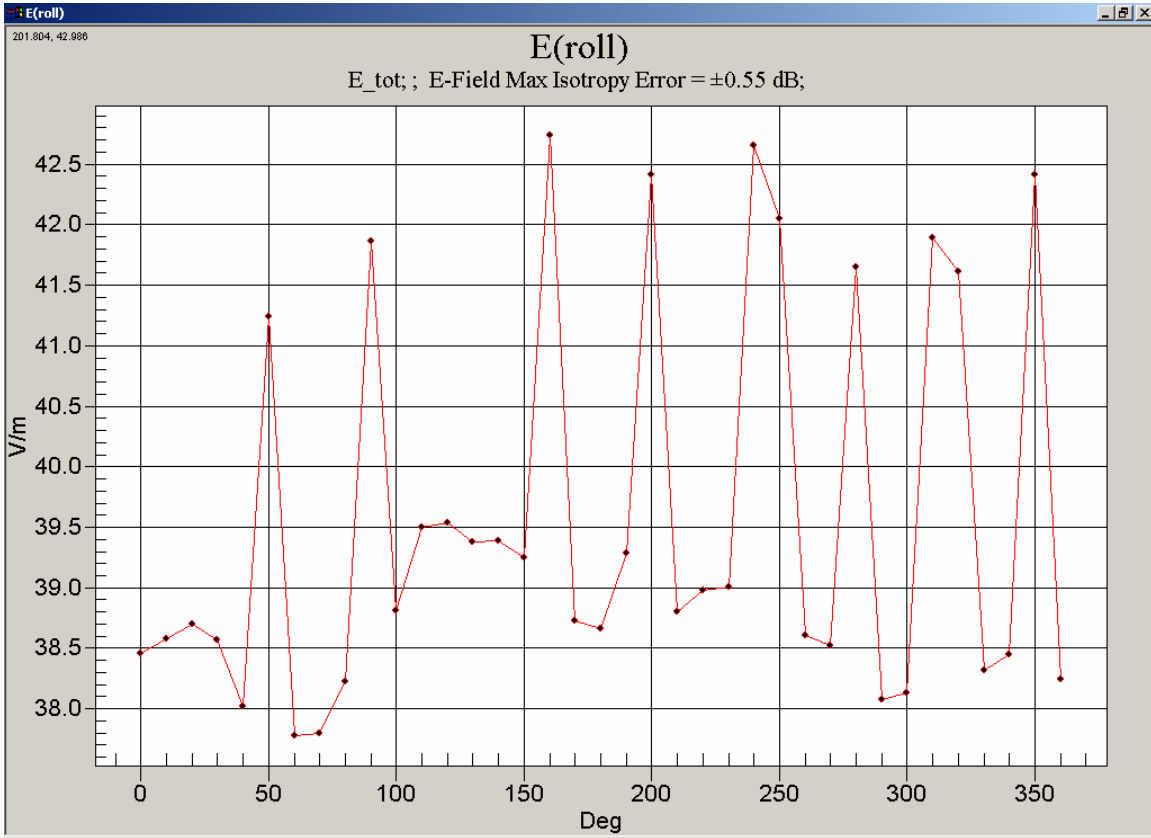


0 dB = 88.6V/m

Location of the probe rotation after applying exclusion blocks

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 11(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

$$\begin{aligned}
E(\text{delta}) &= (E \text{ max} - E \text{ at zero degree}) * \text{PMF} \\
&= (42.8 - 38.4) * 2.10 \\
&= 4.4 * 2.10 \\
&= 9.24 \text{ V/m}
\end{aligned}$$



RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 12(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 19/12/2007 5:19:25 PM

Test Laboratory: RTS

File Name: [HAC E CDMA1900 spkr cent low chan RC1 SO2 FR.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC E Device

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 12/03/2007
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

E Scan - ER probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement grid:
dx=20mm, dy=20mm, dz=5mm
Maximum value of Total (measured) = 46.6 V/m

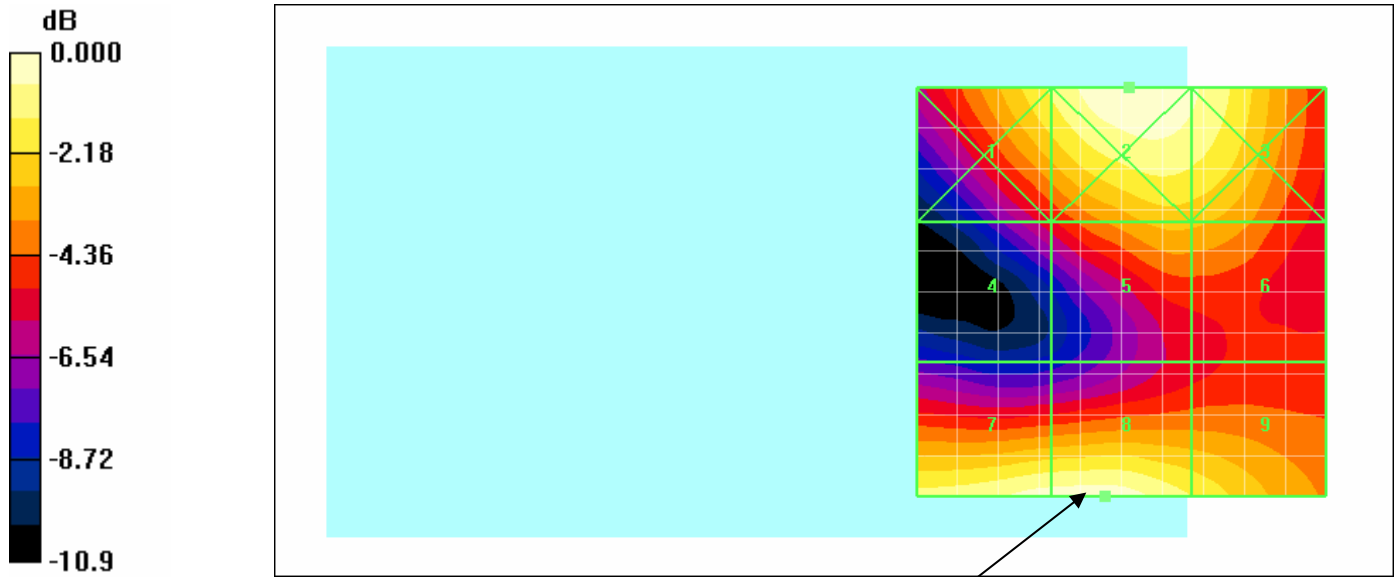
E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm
Probe Modulation Factor = 1.00
Reference Value = 25.6 V/m; Power Drift = 0.033 dB
Maximum value of Total (measured) = 47.9 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 45.8 V/m
Probe Modulation Factor = 0.980
Reference Value = 25.6 V/m; Power Drift = 0.033 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid	Grid	Grid
40.6	47.1	44.1
Grid	Grid	Grid
25.8	34.7	34.4
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 13(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

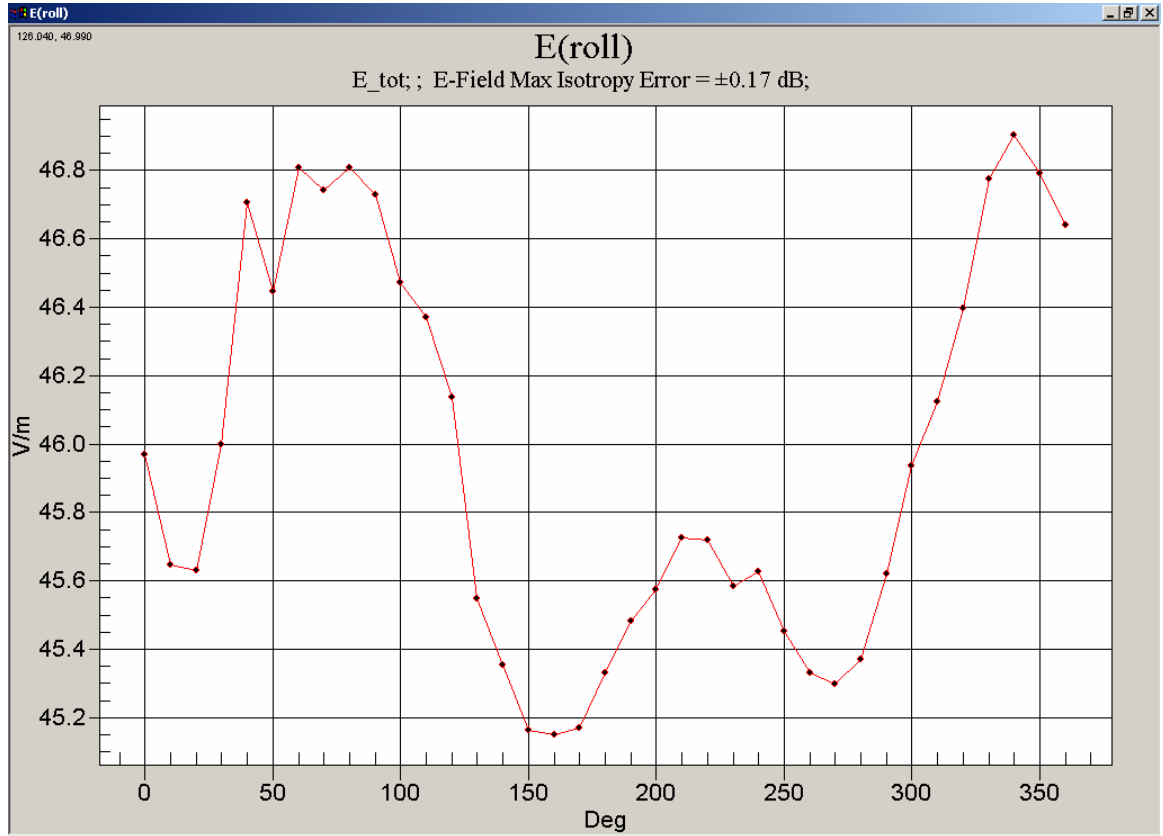


0 dB = 47.1V/m

Location of the probe rotation after the exclusion block

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 14(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

$$\begin{aligned}
E(\text{delta}) &= (E \text{ max} - E \text{ at zero degree}) * \text{PMF} \\
&= (46.80 - 45.95) * 1.58 \\
&= 0.85 * 1.58 \\
&= 1.34 \text{ V/m}
\end{aligned}$$



RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 15(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 9:18:21 PM

Test Laboratory: RTS

File Name: [HAC E CDMA1900 spkr cent mid chan RC1 SO2 FR.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC E Device

Communication System: CDMA 1900; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 12/03/2007
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

E Scan - ER probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement grid:

dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (measured) = 38.7 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 21.2 V/m; Power Drift = 0.117 dB

Maximum value of Total (measured) = 48.9 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 38.2 V/m

Probe Modulation Factor = 0.980

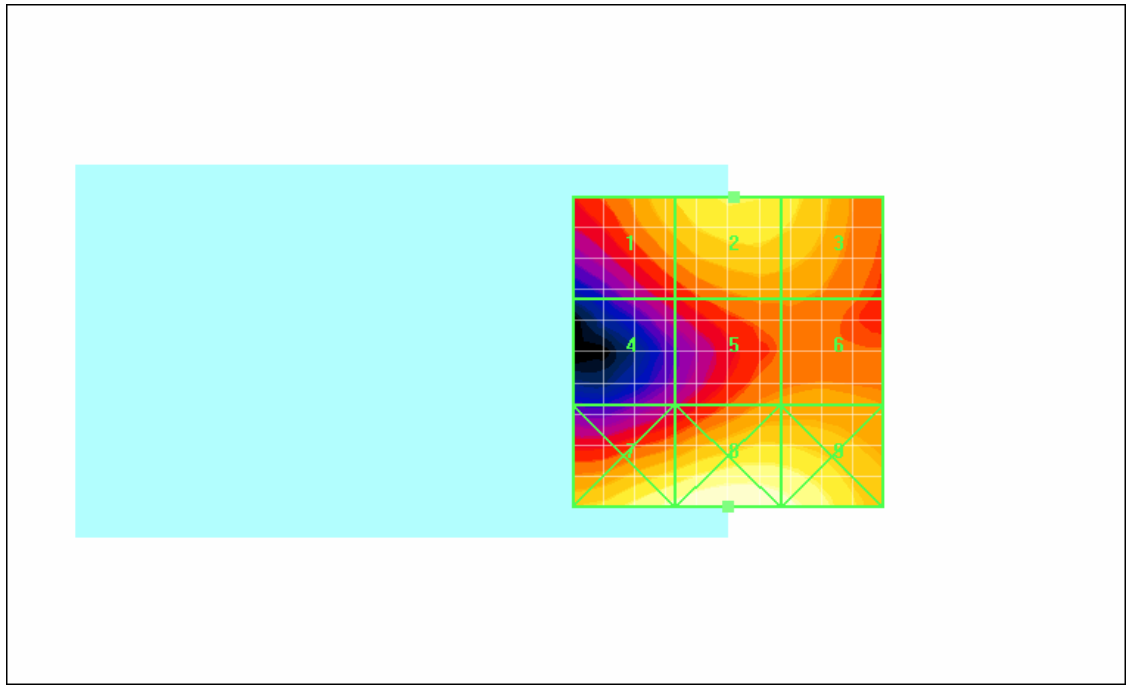
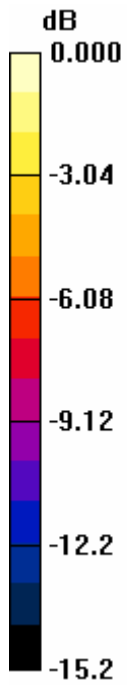
Reference Value = 21.2 V/m; Power Drift = 0.117 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid	Grid	Grid
34.1	38.2	35.8
Grid	Grid	Grid
20.8	27.5	27.9
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 16(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 47.9V/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 17(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 9:03:16 PM

Test Laboratory: RTS

File Name: [HAC E CDMA1900 spkr cent high chan RC1 SO2 FR.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC E Device

Communication System: CDMA 1900; Frequency: 1908.5 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 12/03/2007
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

E Scan - ER probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement grid:

dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (measured) = 34.9 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 18.8 V/m; Power Drift = -0.126 dB

Maximum value of Total (measured) = 49.7 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 34.0 V/m

Probe Modulation Factor = 0.980

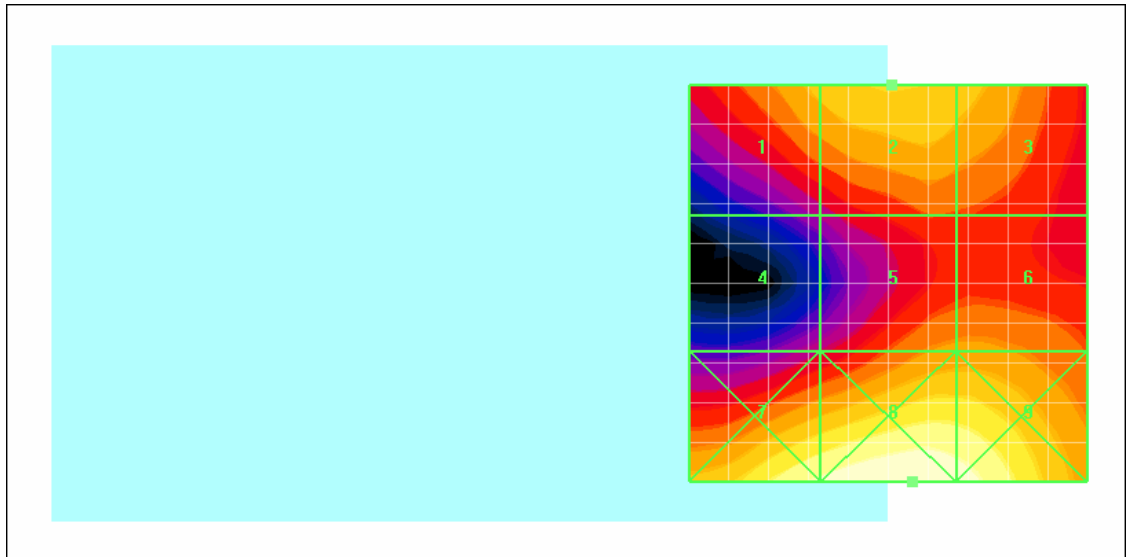
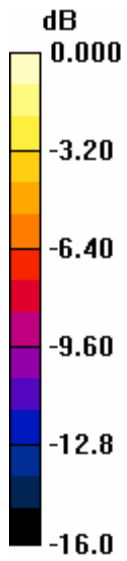
Reference Value = 18.8 V/m; Power Drift = -0.126 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid	Grid	Grid
31.2	34.0	32.0
Grid	Grid	Grid
17.9	27.6	27.7
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 18(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 49.1V/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 19(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 10:00:41 PM

Test Laboratory: RTS

File Name: [HAC E CDMA1900 spkr cent low chan RC3 SO3 FR.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC E Device

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 12/03/2007
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

E Scan - ER probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement grid:
dx=20mm, dy=20mm, dz=5mm
Maximum value of Total (measured) = 38.0 V/m

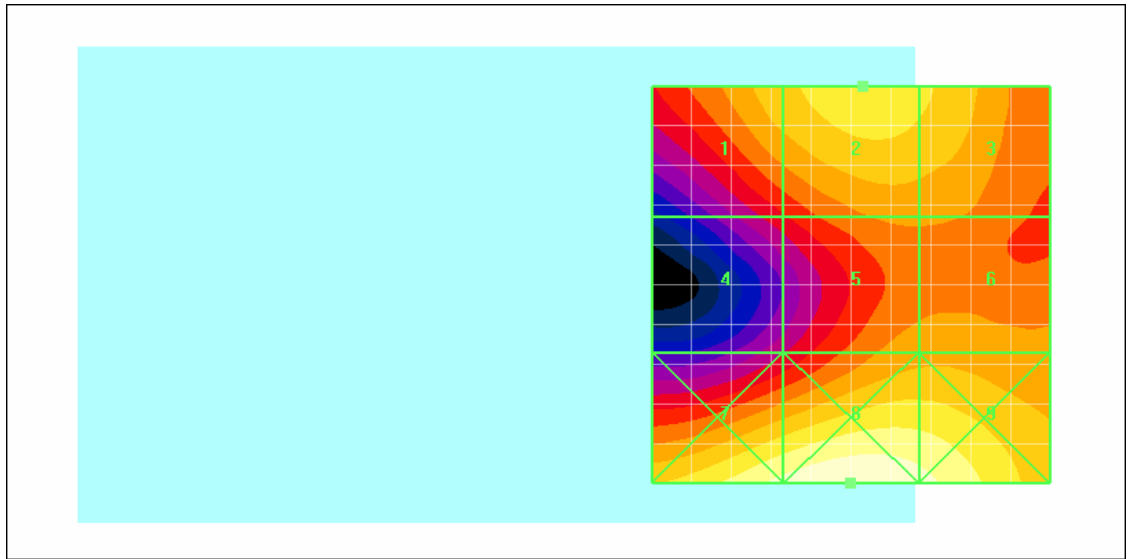
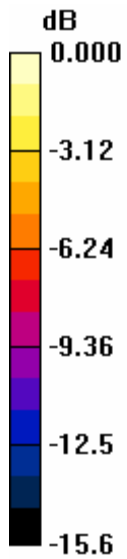
E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm
Probe Modulation Factor = 1.00
Reference Value = 21.7 V/m; Power Drift = -0.040 dB
Maximum value of Total (measured) = 49.0 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 36.8 V/m
Probe Modulation Factor = 0.980
Reference Value = 21.7 V/m; Power Drift = -0.040 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid	Grid	Grid
32.8	36.8	34.7
Grid	Grid	Grid
20.4	28.5	28.8
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 20(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 48.0V/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 21(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 9:52:25 PM

Test Laboratory: RTS

File Name: [HAC E CDMA1900 spkr cent low chan RC3 SO2 FR.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC E Device

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1
 Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
 Phantom section: E Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 12/03/2007
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

E Scan - ER probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement grid:
 dx=20mm, dy=20mm, dz=5mm
 Maximum value of Total (measured) = 37.5 V/m

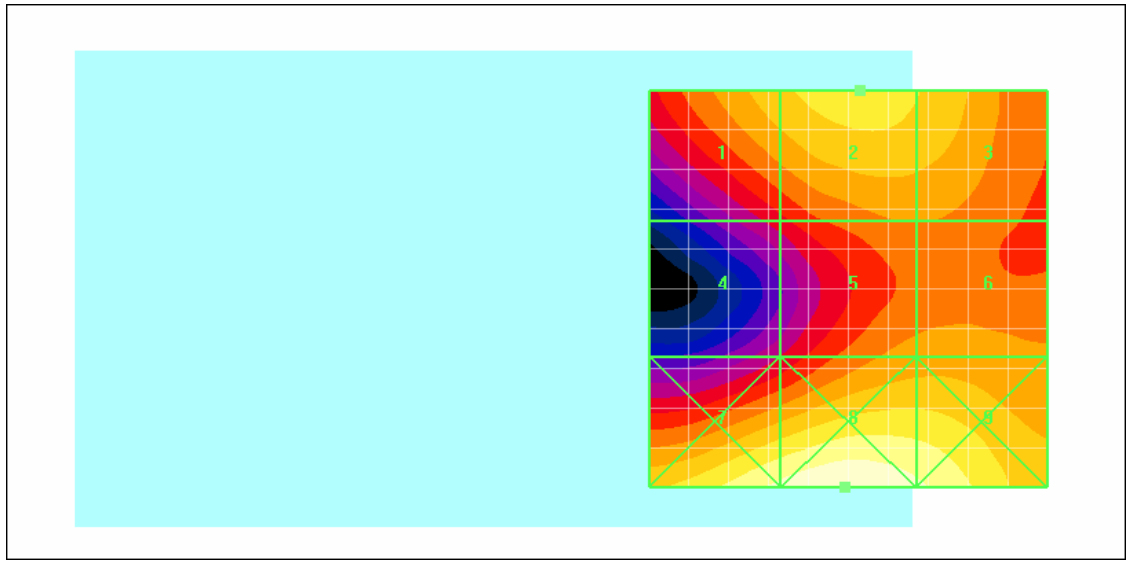
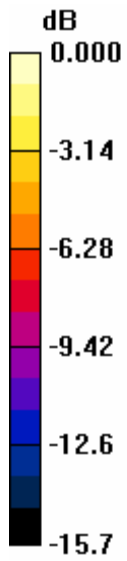
E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm
 Probe Modulation Factor = 1.00
 Reference Value = 21.4 V/m; Power Drift = 0.295 dB
 Maximum value of Total (measured) = 49.8 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
 Maximum value of peak Total field = 36.3 V/m
 Probe Modulation Factor = 0.980
 Reference Value = 21.4 V/m; Power Drift = 0.295 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid	Grid	Grid
33.1	36.3	34.3
Grid	Grid	Grid
20.2	28.3	28.7
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 22(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 48.8V/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 23(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 9:44:09 PM

Test Laboratory: RTS

File Name: [HAC E CDMA1900 spkr cent low chan RC2 SO9 FR.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC E Device

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 12/03/2007
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

E Scan - ER probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement grid:

dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (measured) = 37.4 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 21.6 V/m; Power Drift = 0.103 dB

Maximum value of Total (measured) = 49.2 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 36.3 V/m

Probe Modulation Factor = 0.980

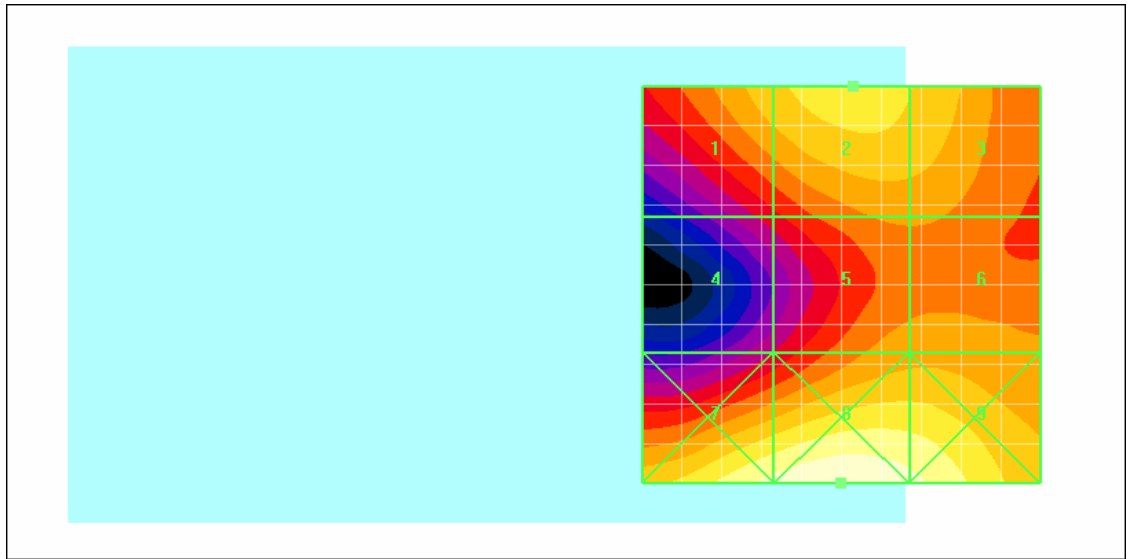
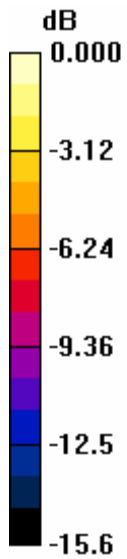
Reference Value = 21.6 V/m; Power Drift = 0.103 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid	Grid	Grid
32.7	36.3	33.9
Grid	Grid	Grid
20.1	28.5	28.8
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 24(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 48.2V/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 25(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 07/01/2008 9:38:39 AM

Test Laboratory: RTS

File Name: [HAC E CDMA1900 spkr cent low chan RC1 SO3 1/8th 01 07 08.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC E Device

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:8

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 12/03/2007
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

E Scan - ER probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement grid:

dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (measured) = 15.0 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 8.20 V/m; Power Drift = 0.175 dB

Maximum value of Total (measured) = 18.9 V/m

E Scan - ER probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 40.3 V/m

Probe Modulation Factor = 2.72

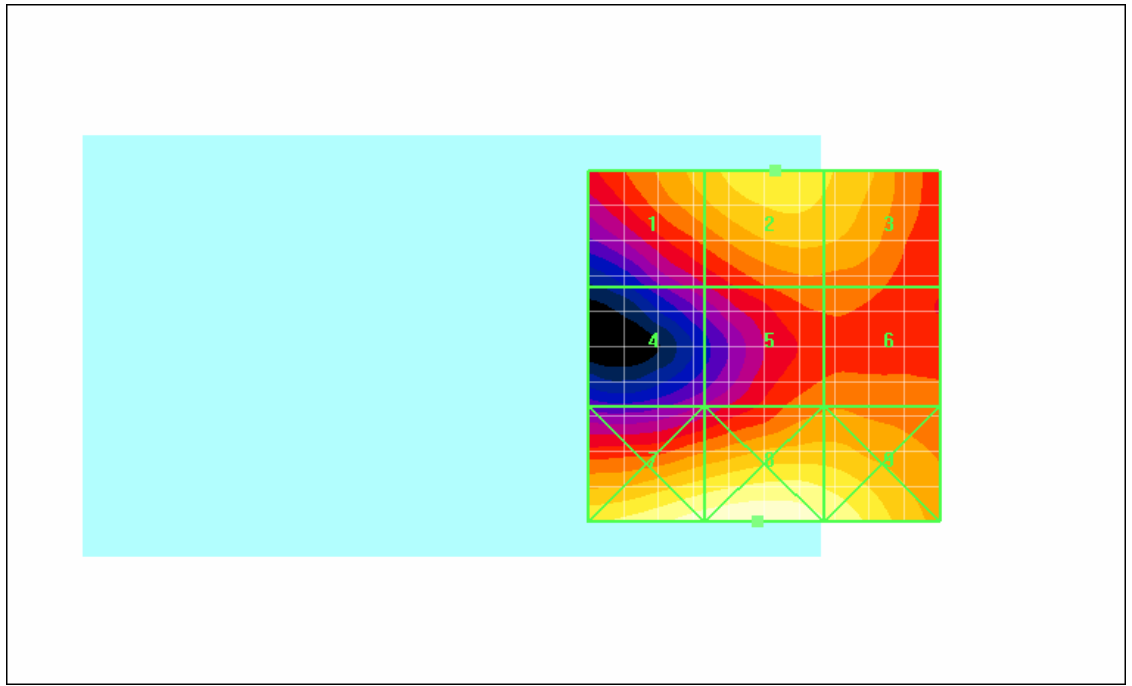
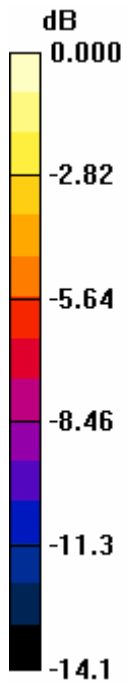
Reference Value = 8.20 V/m; Power Drift = 0.175 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid	Grid	Grid
35.5	40.3	38.1
Grid	Grid	Grid
21.4	29.4	29.7
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 26(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 51.5V/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 27(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 5:57:05 PM

Test Laboratory: RTS

File Name: [HAC H CDMA800 spkr cent low chan RC1 SO2 FR.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC H Device

Communication System: CDMA 800; Frequency: 824.7 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/09/2008
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 0.073 A/m; Power Drift = 0.023 dB

Maximum value of Total (measured) = 0.146 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement

grid: dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (measured) = 0.144 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.095 A/m

Probe Modulation Factor = 0.940

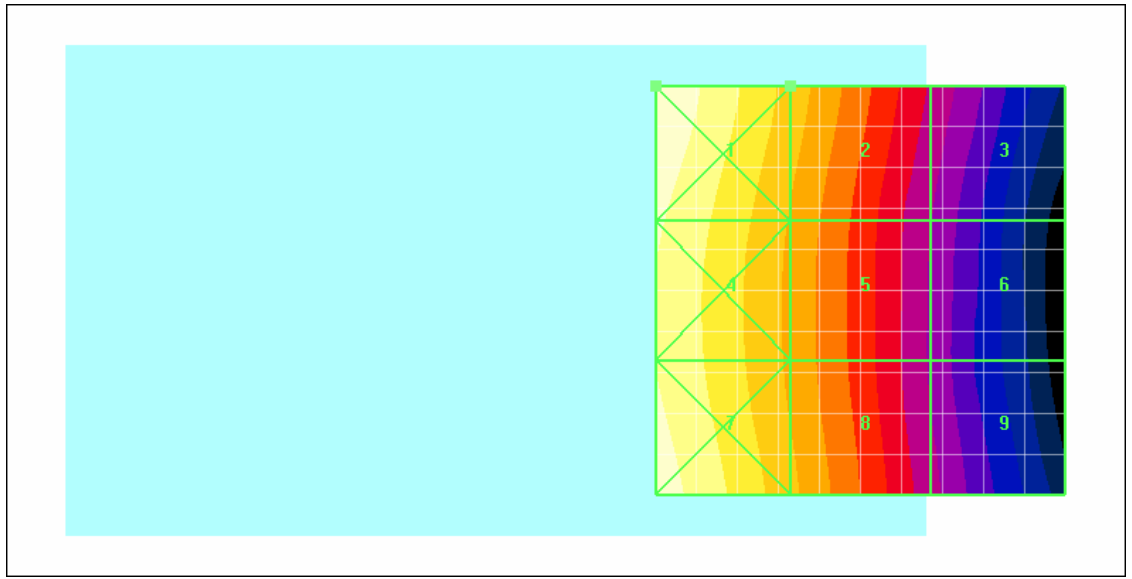
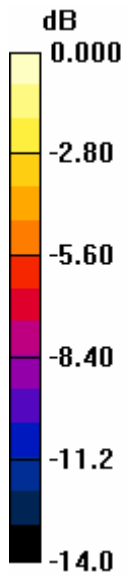
Reference Value = 0.073 A/m; Power Drift = 0.023 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid	Grid	Grid
0.137	0.095	0.058
Grid	Grid	Grid
0.125	0.088	0.053
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 28(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 0.137A/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 29(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 6:04:49 PM

Test Laboratory: RTS

File Name: [HAC H CDMA800 spkr cent mid chan RC1 SO2 FR.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC H Device

Communication System: CDMA 800; Frequency: 836.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/09/2008
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 0.078 A/m; Power Drift = -0.055 dB

Maximum value of Total (measured) = 0.151 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement

grid: dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (measured) = 0.150 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.099 A/m

Probe Modulation Factor = 0.940

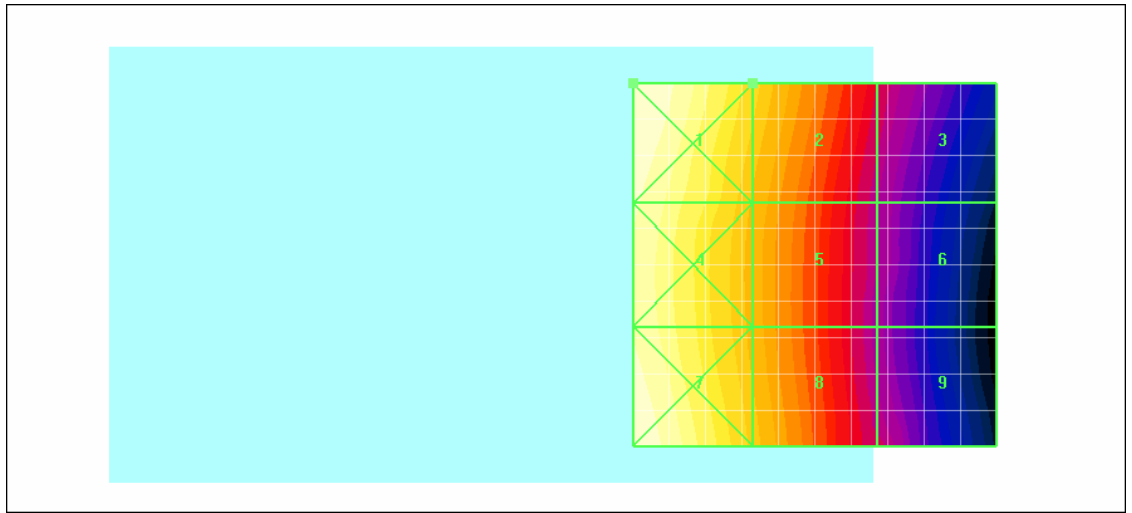
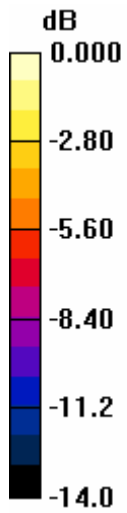
Reference Value = 0.078 A/m; Power Drift = -0.055 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid	Grid	Grid
0.142	0.099	0.060
Grid	Grid	Grid
0.130	0.092	0.055
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 30(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 0.142A/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 31(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 5:16:50 PM

Test Laboratory: RTS

File Name: [HAC H CDMA800 spkr cent high chan RC1 SO2 FR.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC H Device

Communication System: CDMA 800; Frequency: 848.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/09/2008
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 0.085 A/m; Power Drift = -0.110 dB

Maximum value of Total (measured) = 0.161 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement

grid: dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (measured) = 0.159 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.106 A/m

Probe Modulation Factor = 0.940

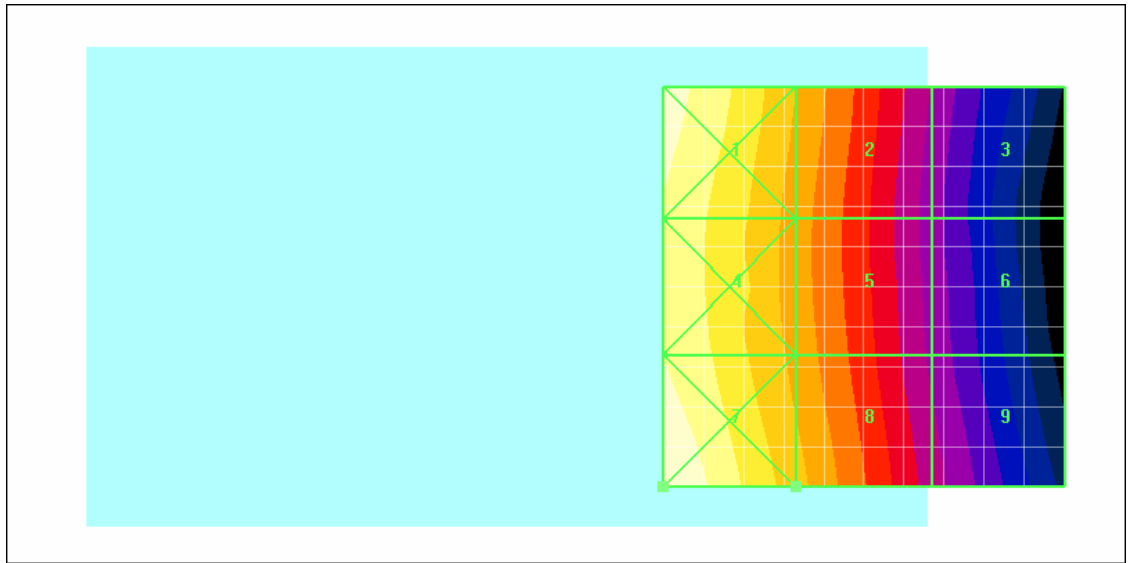
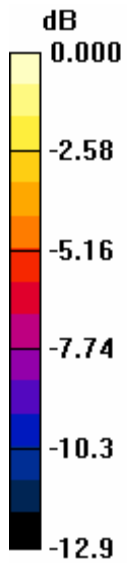
Reference Value = 0.085 A/m; Power Drift = -0.110 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid	Grid	Grid
0.144	0.102	0.062
Grid	Grid	Grid
0.137	0.099	0.061
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 32(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 0.151A/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 33(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 07/01/2008 10:40:44 AM

Test Laboratory: RTS

File Name: [HAC H CDMA800 spkr cent high chan RC1 SO3 1/8th 01 07 08.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC H Device

Communication System: CDMA 800; Frequency: 848.52 MHz; Duty Cycle: 1:8
 Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
 Phantom section: E Device Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/09/2008
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 0.034 A/m; Power Drift = 0.183 dB

Maximum value of Total (measured) = 0.070 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement grid: dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (measured) = 0.065 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.168 A/m

Probe Modulation Factor = 2.41

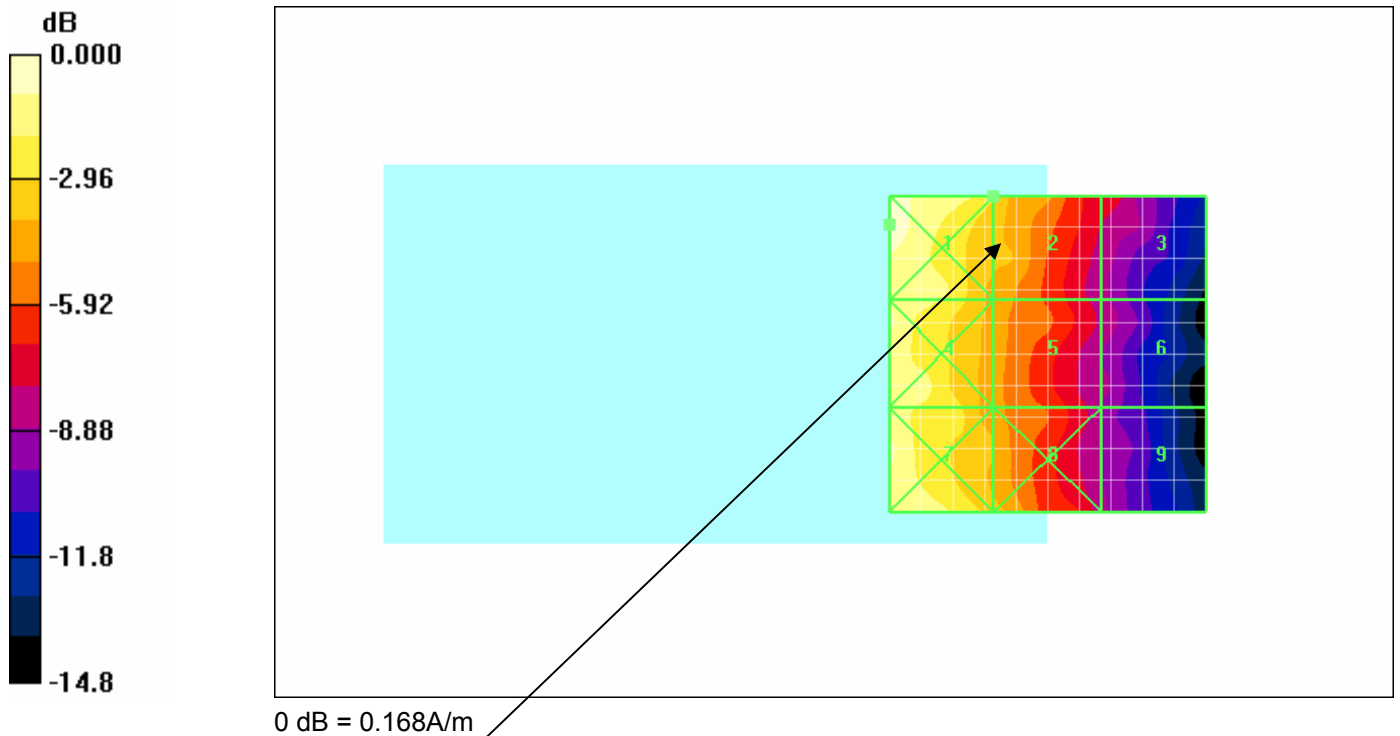
Reference Value = 0.034 A/m; Power Drift = 0.183 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.168	Grid 2 0.121	Grid 3 0.075
Grid 4 0.154	Grid 5 0.103	Grid 6 0.066
Grid 7	Grid 8	Grid 9

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 34(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



Location of the probe rotation after applying exclusion blocks

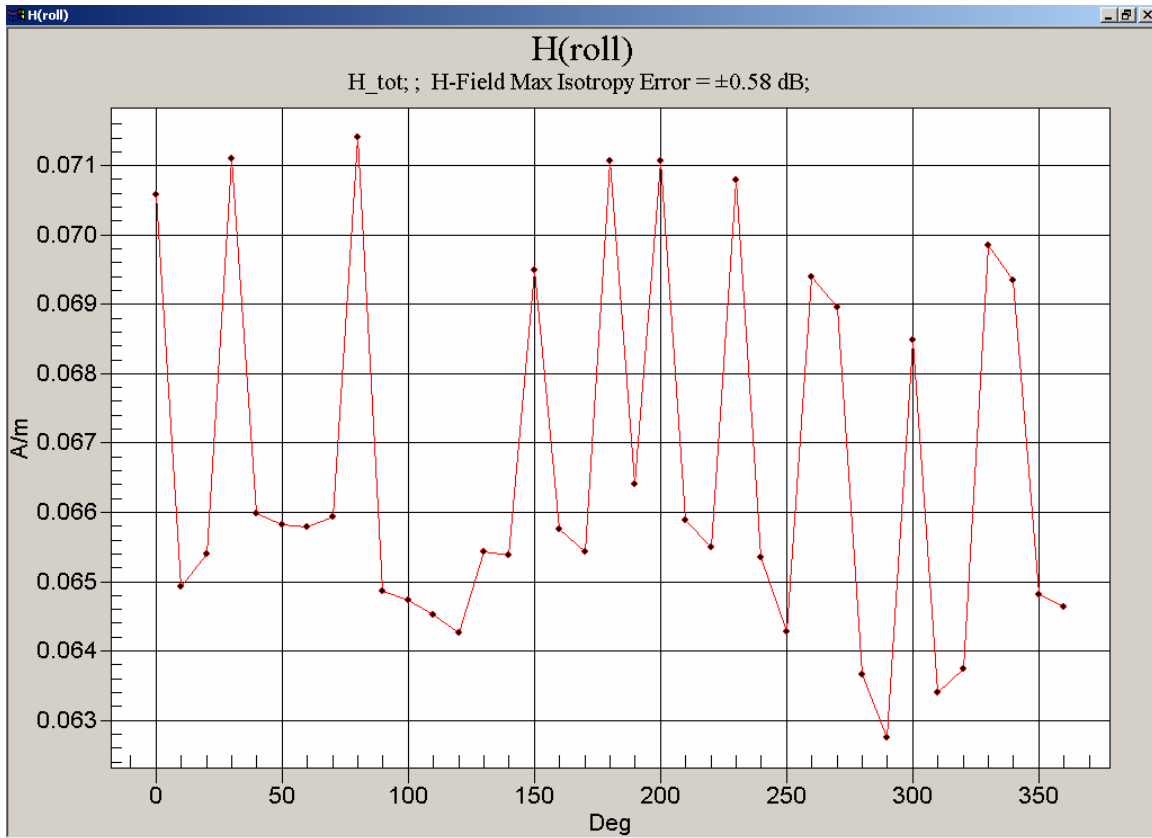
$$\begin{aligned}
E(\Delta) &= (H_{\max} - H_{\text{at zero degree}}) * PMF \\
&= (0.071 - 0.070) * 2.41 \\
&= 0.001 * 2.41 \\
&= 0.002 \text{ A/m}
\end{aligned}$$

Author Data
Daoud Attayi

Dates of Test
08-24 Dec, 07 and 07 Jan, 08

Report No
RTS-0943-0801-03

FCC ID
L6ARBU20CW



RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 36(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 6:52:17 PM

Test Laboratory: RTS

File Name: [HAC H CDMA1900 spkr cent low chan RC1 SO2 FR.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC H Device

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1
 Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
 Phantom section: E Device Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/09/2008
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 0.108 A/m; Power Drift = 0.200 dB

Maximum value of Total (measured) = 0.114 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement grid: dx=20mm, dy=20mm, dz=5mm

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.111 A/m

Probe Modulation Factor = 0.980

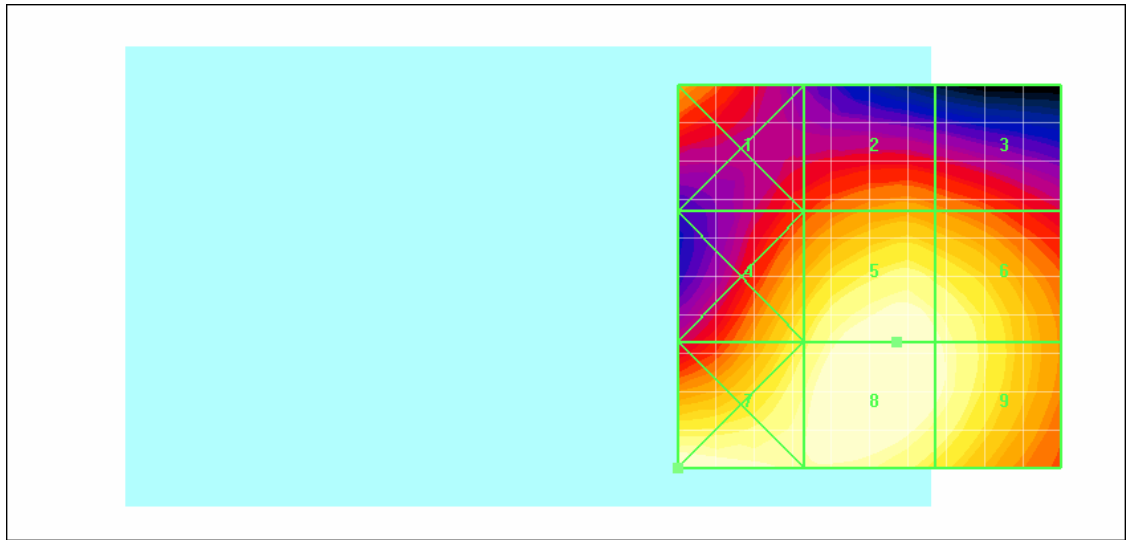
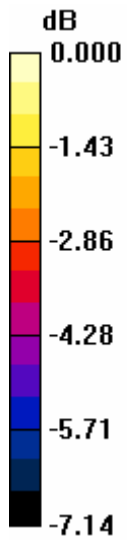
Reference Value = 0.108 A/m; Power Drift = 0.200 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid	Grid	Grid
0.088	0.088	0.086
Grid	Grid	Grid
0.099	0.110	0.107
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 37(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 0.112A/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 38(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 7:09:14 PM

Test Laboratory: RTS

File Name: [HAC H CDMA1900 spkr cent mid chan RC1 SO2 FR.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC H Device

Communication System: CDMA 1900; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/09/2008
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 0.105 A/m; Power Drift = 0.050 dB

Maximum value of Total (measured) = 0.134 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement

grid: dx=20mm, dy=20mm, dz=5mm

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.105 A/m

Probe Modulation Factor = 0.980

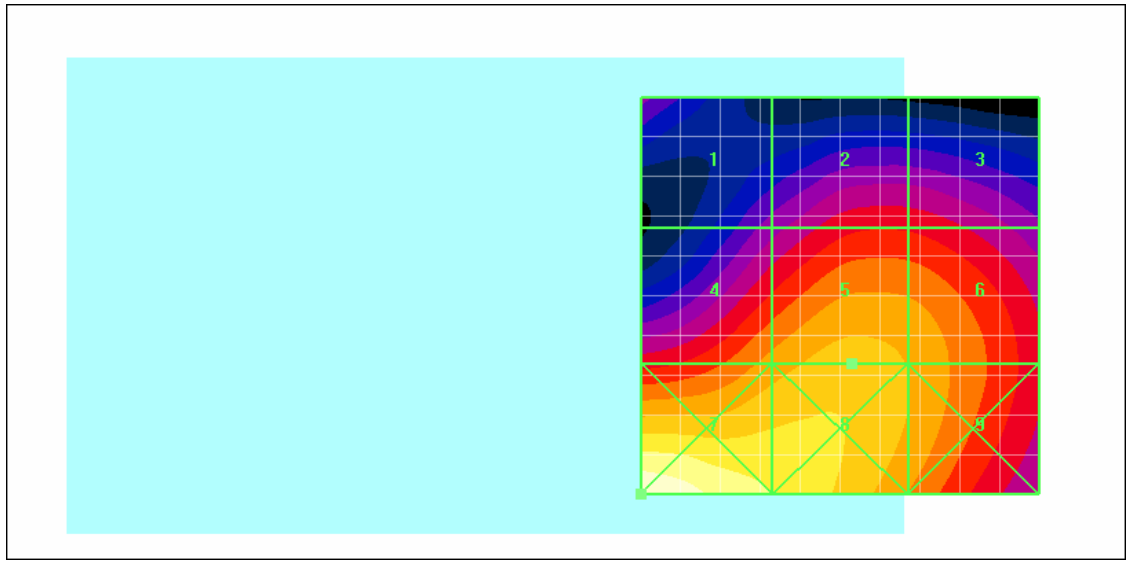
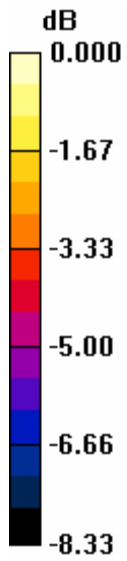
Reference Value = 0.105 A/m; Power Drift = 0.050 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid	Grid	Grid
0.072	0.084	0.083
Grid	Grid	Grid
0.098	0.105	0.101
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 39(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 0.131A/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 40(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 6:31:56 PM

Test Laboratory: RTS

File Name: [HAC H CDMA1900 spkr cent high chan RC1 SO2 FR.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC H Device

Communication System: CDMA 1900; Frequency: 1908.5 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/09/2008
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 0.103 A/m; Power Drift = 0.139 dB

Maximum value of Total (measured) = 0.133 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement

grid: dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (measured) = 0.135 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.103 A/m

Probe Modulation Factor = 0.980

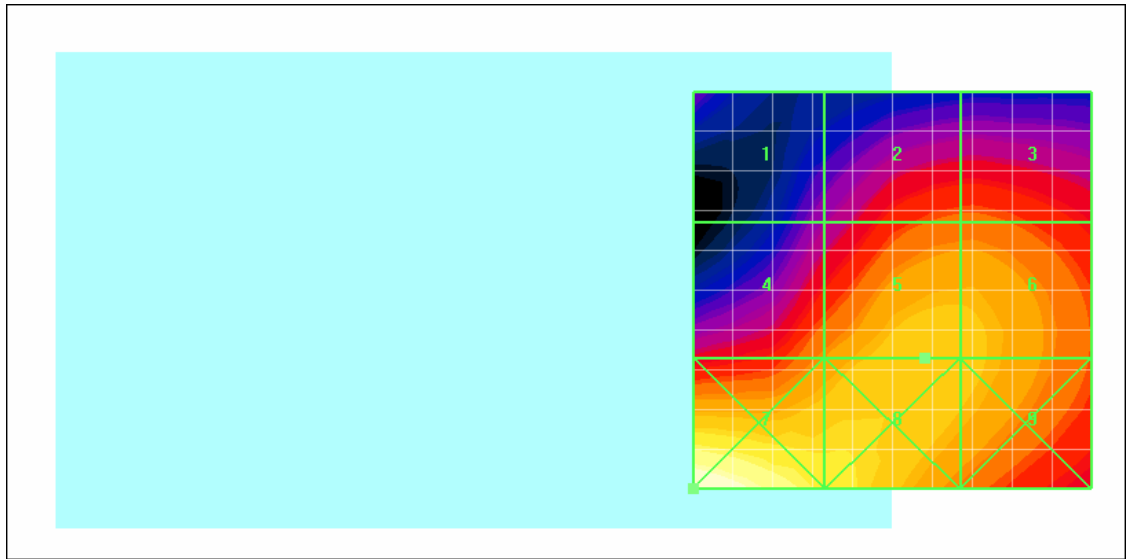
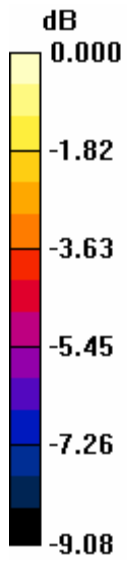
Reference Value = 0.103 A/m; Power Drift = 0.139 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid	Grid	Grid
0.070	0.088	0.088
Grid	Grid	Grid
0.093	0.103	0.101
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 41(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 0.131A/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 42(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 8:31:14 PM

Test Laboratory: RTS

File Name: [HAC H CDMA1900 spkr cent low chan RC3 SO2 FR.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC H Device

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/09/2008
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 0.107 A/m; Power Drift = -0.050 dB

Maximum value of Total (measured) = 0.141 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement

grid: dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (measured) = 0.138 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.109 A/m

Probe Modulation Factor = 0.980

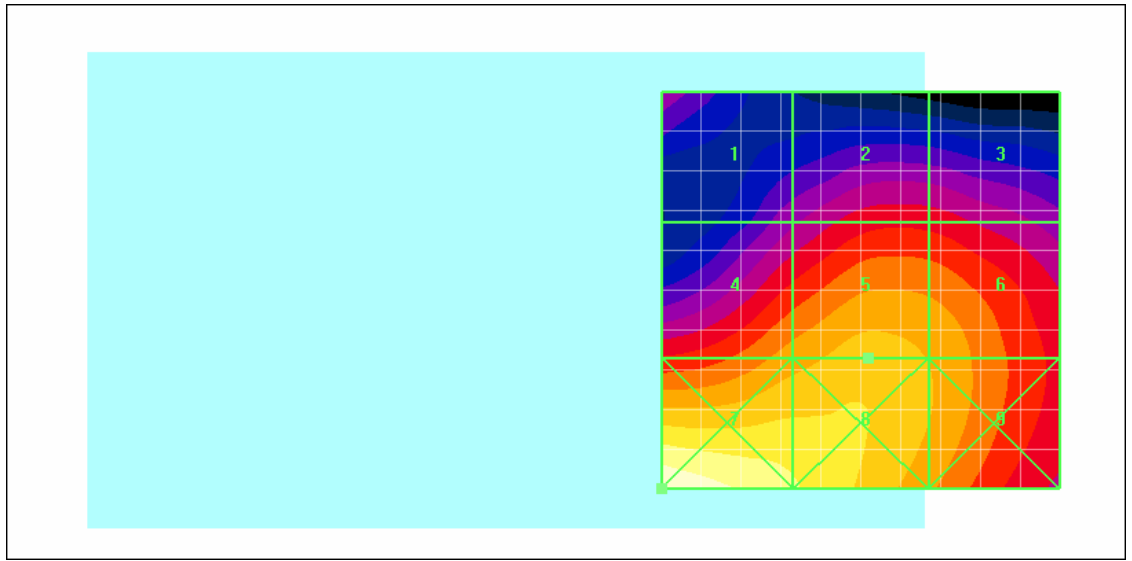
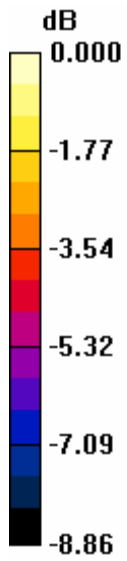
Reference Value = 0.107 A/m; Power Drift = -0.050 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid	Grid	Grid
0.075	0.085	0.084
Grid	Grid	Grid
0.102	0.109	0.105
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 43(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 0.138A/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 44(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 8:41:48 PM

Test Laboratory: RTS

File Name: [HAC H CDMA1900 spkr cent low chan RC3 SO3 FR.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC H Device

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/09/2008
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 0.108 A/m; Power Drift = -0.064 dB

Maximum value of Total (measured) = 0.140 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement

grid: dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (measured) = 0.139 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.109 A/m

Probe Modulation Factor = 0.980

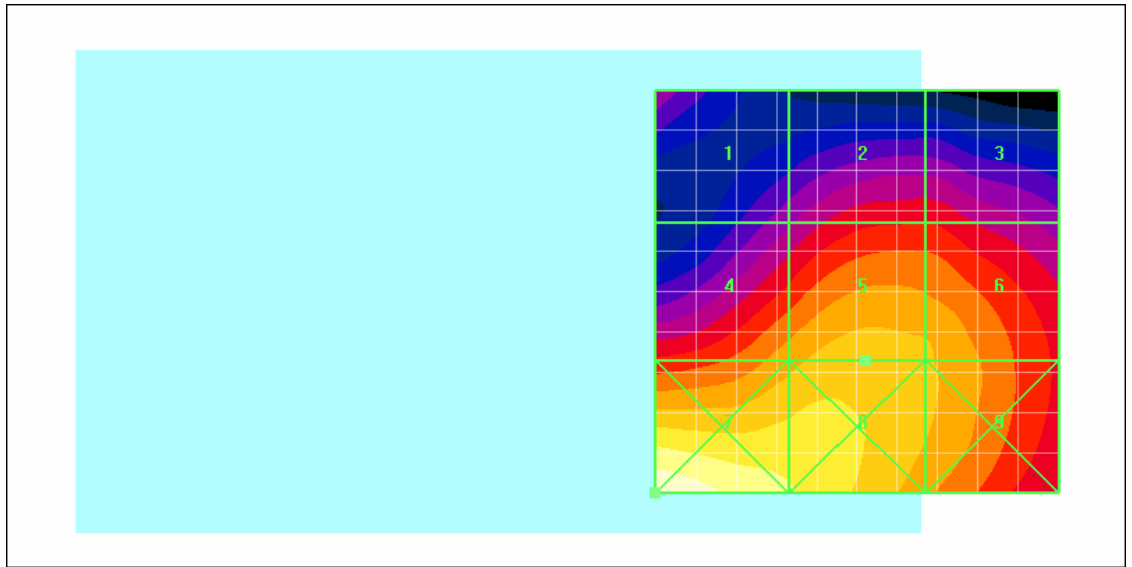
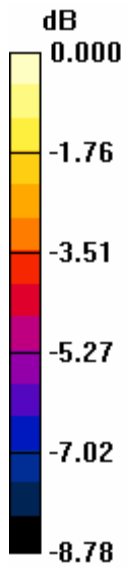
Reference Value = 0.108 A/m; Power Drift = -0.064 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid	Grid	Grid
0.075	0.086	0.086
Grid	Grid	Grid
0.102	0.109	0.106
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 45(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 0.137A/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 46(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 18/12/2007 7:49:39 PM

Test Laboratory: RTS

File Name: [HAC H CDMA1900 spkr cent low chan RC2 SO9 FR.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC H Device

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/09/2008
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 0.105 A/m; Power Drift = 0.040 dB

Maximum value of Total (measured) = 0.136 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement

grid: dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (measured) = 0.137 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.106 A/m

Probe Modulation Factor = 0.980

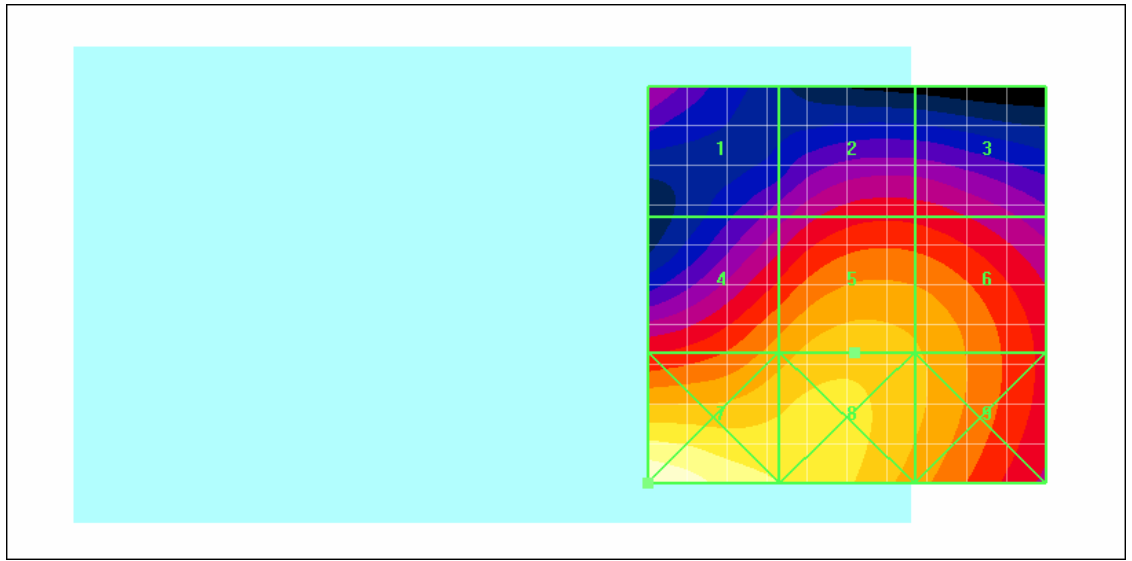
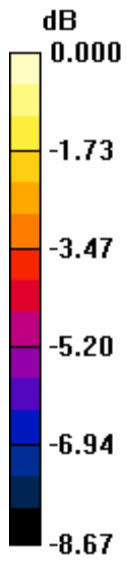
Reference Value = 0.105 A/m; Power Drift = 0.040 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid	Grid	Grid
0.074	0.083	0.082
Grid	Grid	Grid
0.099	0.106	0.103
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 47(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03



0 dB = 0.133A/m

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 48(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

Date/Time: 07/01/2008 11:00:39 AM

Test Laboratory: RTS

File Name: [HAC H CDMA1900 spkr cent low chan RC1 SO3 1/8th 01 07 08.da4](#)

DUT: BlackBerry Smartphone; Type: Sample ; Serial: Not Specified
Program Name: HAC H Device

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:8

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: E Device Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 09/11/2007
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 07/03/2007
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 53; Postprocessing SW: SEMCAD, V1.8 Build 172

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Reference Value = 0.047 A/m; Power Drift = -0.025 dB

Maximum value of Total (measured) = 0.048 A/m

H Scan - H3DV5 probe tip 10mm above Device Reference/Z Scan (1x1x21): Measurement

grid: dx=20mm, dy=20mm, dz=5mm

H Scan - H3DV5 probe tip 10mm above Device Reference/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.115 A/m

Probe Modulation Factor = 2.40

Reference Value = 0.047 A/m; Power Drift = -0.025 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

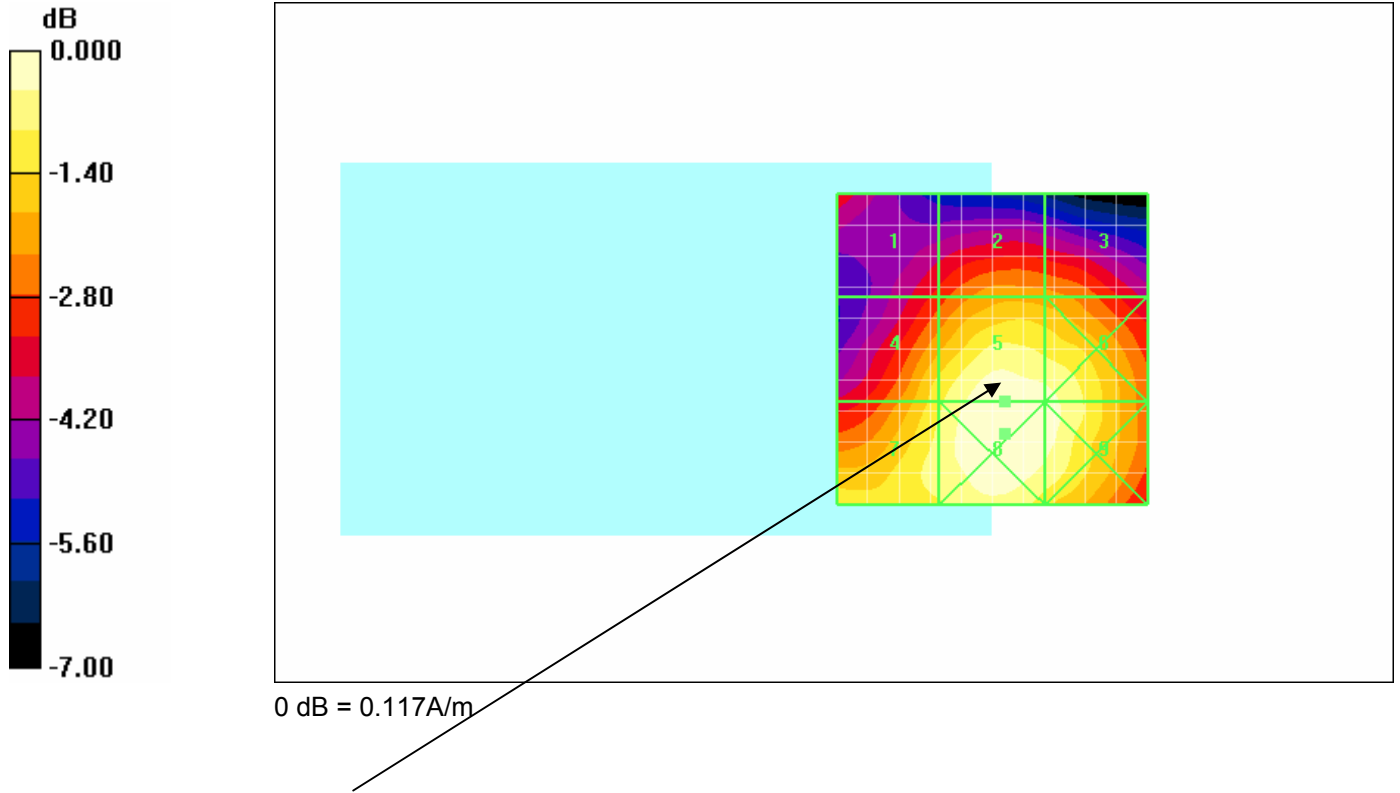
Grid	Grid	Grid
0.083	0.093	0.092
Grid	Grid	Grid
0.104	0.115	0.113
Grid	Grid	Grid

RTS RIM Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for BlackBerry® Smartphone Model RBU21CW		Page 49(50)
	Author Data Daoud Attayi	Dates of Test 08-24 Dec, 07 and 07 Jan, 08	Report No RTS-0943-0801-03

H Scan - H3DV5 probe tip 10mm above Device Reference/Z Scan (1x1x31):

Measurement grid: dx=20mm, dy=20mm, dz=5mm

Maximum value of Total (interpolated) = 0.048 A/m



Location of the probe rotation after applying exclusion blocks

$$\begin{aligned}
E(\delta) &= (H_{\max} - H_{\text{at zero degree}}) * PMF \\
&= (0.0497 - 0.0487) * 2.40 \\
&= 0.001 * 2.40 \\
&= 0.002 \text{ A/m}
\end{aligned}$$

Author Data
Daoud Attayi

Dates of Test
08-24 Dec, 07 and 07 Jan, 08

Report No
RTS-0943-0801-03

FCC ID
L6ARBU20CW

